PH0810-15



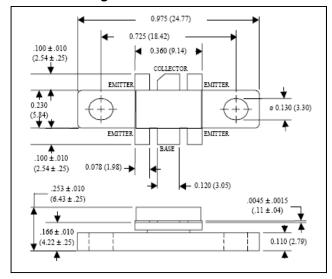
Wireless Power Transistor 15W, 850-960MHz, 26V

M/A-COM Products Released - Rev. 07.07

Features

- Designed for linear amplifier applications
- Class AB: -30 dBc typ. 3rd IMD at 15 W PEP
- Common emitter configuration
- Internal input impedance matching
- Diffused emitter ballasting

Outline Drawing¹



Notes: (unless otherwise specified)

1. Tolerances are: inches ± .005" (millimeters ± 0.13mm)

ABSOLUTE MAXIMUM RATING AT 25°C

Parameter	Symbol	Rating	Units
Collector-Base Voltage	V _{CBO}	60	V
Collector-Emitter Voltage	V _{CES}	60	V
Emitter-Base Voltage	V _{EBO}	3.0	V
Collector Current	I _c	1.8	Α
Dissipation @ 25°C	P _D	43	W
Storage Temperature	T _{stg}	-55 to +150	°C
Junction Temperature	T _j	200	°C
Thermal Resistance	θj _c	3.5	°C/W

ELECTRICAL SPECIFICATIONS AT 25°C

Symbol	Parameter	Test Conditions	Min	Max	Units
BV _{CES}	Collector-Emitter Breakdown	I _c =15mA	60	-	V
I _{CES}	Collector-Emitter Leakage	V _{CE} =24.0 V	-	2.0	mΑ
BV _{CEO}	Collector-Emitter Breakdown	I _c =40 mA	24	-	V
BV _{EBO}	Emitter-Base Breakdown	I _B =2.5 mA	3.0	-	V
h _{FE}	DC Forward Current Gain	V _{CE} =5.0 V, I _C =0.5 A	15	120	-
G _P	Power Gain	V _{cc} =24 V, I _{cq} =100 mA, Pout= 15W, f=900 MHz	12	-	dB
η	Collector Efficiency	V _{cc} =24 V, I _{cq} =100 mA, Pout= 15W, f=900 MHz	50	-	%
R _L	Input Return Loss	V _{cc} =24 V, I _{cq} =100 mA, Pout=15W, f=900 MHz	10	-	dB
VSWR	Load Mismatch Tolerance	V _{cc} =24 V, I _{cq} =100 mA, Pout=15W PEP, f=900 MHz, Δf=100 kHz	-	10:1	-
IMD ₃	3rd Order IMD	V _{cc} =24 V, I _{cq} =100 mA, Pout=15W PEP, f=900 MHz, Δf=100 kHz	-	-30	dBc

[•] Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300

Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298
 Visit www.macomtech.com for additional data sheets and product information.

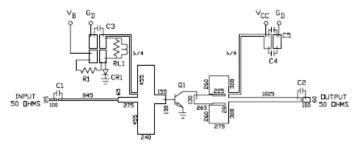
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ELECTRICAL SCHEMATIC

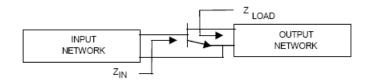


Notes:

1. Dimensions are in mils.

ELECTRICAL SCHEMATIC PARTS LIST

C1, C2, C3	100 pF ATC Size A
C4	5000 pF ATC Size B
C5	50 uF 50 Volts
CR1	Diode cathode tied to flange (Harris 1N4245)
Q1	PH0810-15
R1	5 Ohms ¼ W
RL1	10T / No. 22 AWG on 3.1 Ohm 1/4 Watt
Board Type	Rogers 6010.5 .025" thick, E _R = 10.5



TYPICAL OPTIMUM DEVICE IMPEDANCE

F (MHz)	Z _{in} (Ω)	Z _{load} (Ω)
850	2.5 + j3.6	4.3 + j2.6
900	2.9 + j2.4	4.4 + j3.4
960	1.5 + i2.0	4.3 + j3.9

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